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NTE1570 (NPN Tuner) & NTE1572 (FET Tuner) Integrated Circuit TV Video IF, Sound IF

Functions:

PIF

- Three Controlled IF Amplifier Stages
- Video Demodulator Controlled by Picture Carrier
- Black Noise and White Noise Inverter
- Peak AGC
- DC Amplifier for RF AGC Out

SIF

- Three Differential IF Amplifier Stages
- Phase Detector
- DC Controlled Attenuator
- Audio Amplifier Stage with NFB Terminal

Features:

- PIF, SIF, ATT Audio Driver
- 2 Chip Color TV System is Possible with NTE1547

PIF

- High Gain, Wide Band IF Amplifier
- AGC Characteristics with Excellent Stability
- Excellent DG/DP Characteristics
- Excellent S/N Characteristics due to Delayed 3 Stage AGC Action
- Negative Video Output Signal
- Switch Off the Video Part with VTR Switch

SIF

- Excellent Limiter Characteristics
- Excellent Attenuator Characteristics

Absolute Maximum Ratings: ($T_A = +25^\circ\text{C}$ unless otherwise specified)

| | |
|--|-------------------------------------|
| Supply Voltage, V_{CC} | 15V |
| Pin11 Open Voltage, V_{11} | 15V |
| Video DC Output Current, I_{15} | 6mA |
| Audio DC Output Current, I_3 | 3mA |
| Pin2 Voltage, V_2 | 15V |
| Power Dissipation, P_D | 1.6W |
| Derate Above 25°C | 12.8mW/ $^\circ\text{C}$ |
| Operating Temperature Range, T_{opr} | -20° to $+65^\circ\text{C}$ |
| Storage Temperature range, T_{stg} | -55° to $+150^\circ\text{C}$ |

Electrical Characteristics: ($T_A = +25^\circ\text{C}$, $V_{CC} = 12\text{V}$, $f_p = 58.75\text{MHz}$, $f_S = 54.25\text{MHz}$)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|--|----------------------------------|--------------------|------|------|------|----------------------------|
| PIF Section | | | | | | |
| Recommended Supply Voltage | V_{CC} | | 10.8 | 12.0 | 13.2 | V |
| Supply Current | I_{CC} | | 50 | 72 | 95 | mA |
| Video DC Output Voltage NTE1570 | V_{15} | $SW_1: 2, SW_2: 2$ | 5.2 | 5.5 | 5.8 | V |
| NTE1572 | | $SW_1: 1, SW_2: 2$ | | | | |
| AFT DC Output Voltage NTE1570 | V_{13} | $SW_1: 2, SW_2: 2$ | 5.3 | 6.8 | 8.3 | V |
| NTE1572 | | $SW_1: 1, SW_2: 2$ | | | | |
| NTE1570 | V_{14} | $SW_1: 2, SW_2: 2$ | | | | |
| NTE1572 | | $SW_1: 1, SW_2: 2$ | | | | |
| AFT DC Offset Voltage NTE1570 | ΔV_{13-14} | $SW_1: 2, SW_2: 2$ | -1.5 | 0 | +1.5 | V |
| NTE1572 | | $SW_1: 1, SW_2: 2$ | | | | |
| RF AGC Residual Output Voltage NTE1570 | $V_{11(\text{sat})}$ | $SW_1: 2, SW_2: 2$ | - | - | 0.5 | V |
| NTE1572 | | $SW_1: 1, SW_2: 2$ | | | | |
| RF AGC Leakage Current NTE1570 | $I_{11(\text{leak})}$ | $SW_1: 2, SW_2: 1$ | - | - | 1.0 | μA |
| NTE1572 | | $SW_1: 1, SW_2: 1$ | | | | |
| Video Sensitivity (Pin7–Pin8) | v_i | Note 1 | 60 | 150 | 250 | μV_{rms} |
| AGC Range | ΔA_{PIF} | Note 2 | 60 | 64 | - | dB |
| Sync Tip Level Voltage (V_{15}) | V_{SYNC} | Note 3 | 2.3 | 2.5 | 2.7 | V |
| Maximum IF Input Voltage (PIF) | $i_{\text{IN}(\text{MAX})}$ | Note 4 | 100 | 120 | - | mV_{rms} |
| White Noise Threshold Level (V_{15}) | V_{WTH} | Note 5 | 5.8 | 6.2 | 6.6 | V |
| White Noise Clamp Level (V_{15}) | V_{WCL} | Note 5 | 3.7 | 4.1 | 4.5 | V |
| Black Noise Threshold Voltage (V_{15}) | V_{BTH} | Note 5 | 1.4 | 1.6 | 1.8 | V |
| Black Noise Clamp Level (V_{15}) | V_{BCL} | Note 5 | 2.9 | 3.3 | 3.7 | V |
| Video Frequency Response | f_{BW} | Note 6 | 4.5 | 5.5 | - | MHz |
| Suppression of Carrier | CL | Note 7 | 40 | 50 | - | dB |
| Suppression of 2 nd Carrier | $I_{2\text{nd}}$ | Note 8 | 40 | 50 | - | dB |
| 920kHz Beat Level | I_{920} | Note 9 | 33 | 38 | - | dB |
| Differential Phase | DP | Note 10 | - | 3.5 | 5.0 | deg |
| Differential Gain | DG | Note 10 | - | 7 | 10 | % |
| PIF Input Impedance | $R_{\text{IN}(\text{PIF})}$ | Note 11 | 1.5 | 3.0 | 6.0 | k Ω |
| PIF Input Capacitance | $C_{\text{IN}(\text{PIF})}$ | Note 11 | - | 3 | 10 | pF |
| AFT Output Voltage Upper | $V_{13\text{U}}, V_{14\text{U}}$ | Note 13 | 11.7 | 11.9 | 12.0 | V |
| Lower | $V_{13\text{L}}, V_{14\text{L}}$ | | 1.8 | 2.3 | 2.8 | V |

Electrical Characteristics (Cont'd): ($T_A = +25^\circ\text{C}$, $V_{CC} = 12\text{V}$, $f_p = 58.75\text{MHz}$, $f_S = 54.25\text{MHz}$)

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|---|----------------------|---|------|------|------|----------------------------|
| RF AGC Maximum Available Current NTE1570 | $I_{4(\text{max})}$ | SW ₁ : 2, SW ₂ : 1 | 7.0 | – | – | mA |
| NTE1572 | | SW ₁ : 1, SW ₂ : 1 | 0.3 | – | – | mA |
| RF AGC Delay Setting Range (Delay) | V_{IN} | Note 14 | 5 | 7 | 9 | V |
| AFT Band Width | ΔF_W | Note 13 | 1.4 | – | – | MHz |
| Video Output Voltage | V_{OUT} | Note 15 | 2.25 | 2.50 | 2.75 | V |
| SIF Output Voltage | S_{OUT} | Note 16 | 200 | 400 | 600 | mV _{rms} |
| SIF Section | | | | | | |
| Input Limiting Voltage | $V_{IN(\text{LIM})}$ | $R_D = \infty$, Note 17 | – | 200 | 400 | μV_{rms} |
| AM Rejection Ratio | AMR | SIF IN: $f = 4.5\text{MHz}$, $f_m = 400\text{Hz}$, $\Delta f = \pm 25\text{kHz}$, AM: 30%, $v_{in} = 100\text{dB}\mu$ | 40 | 45 | – | dB |
| Recovered Output Voltage | V_{OD} | SIF IN: $f = 4.5\text{MHz}$, $f_m = 400\text{Hz}$, $\Delta f = \pm 25\text{kHz}$, $v_{in} = 80\text{dB}\mu$, $R_D = 12\text{k}\Omega$ | 0.5 | 0.75 | – | V_{rms} |
| Total Harmonic Distortion | THD | SIF IN: $f = 4.5\text{MHz}$, $f_m = 400\text{Hz}$, $\Delta f = \pm 25\text{kHz}$, $v_{in} = 80\text{dB}\mu$ | – | 1.0 | – | % |
| Max. Audio Output Voltage | V_{OM} | SIF IN: $f = 4.4$ to 4.6MHz | 4.0 | – | – | V_{P-P} |
| SIF Input Impedance | $R_{IN(\text{SIF})}$ | $f = 4.5\text{MHz}$ | 10 | 20 | 30 | $\text{k}\Omega$ |
| SIF Input Capacitance | $C_{IN(\text{SIF})}$ | $f = 4.5\text{MHz}$ | – | 3.0 | – | pF |
| DET Output Impedance | $R_{O(\text{DET})}$ | Note 18 | 10 | 15 | 20 | $\text{k}\Omega$ |
| DC Voltage, Pin21 NTE1570 | V_{21} | SW ₁ : 2, SW ₂ : 2 | 3.5 | 4.4 | 5.3 | V |
| NTE1572 | | SW ₁ : 1, SW ₂ : 2 | 3.5 | 4.4 | 5.3 | V |
| DC Voltage, Pin23 NTE1570 | V_{23} | SW ₁ : 2, SW ₂ : 2 | 4.8 | 6.0 | 7.2 | V |
| NTE1572 | | SW ₁ : 1, SW ₂ : 2 | 4.8 | 6.0 | 7.2 | V |
| DC Voltage, Pin1 NTE1570 | V_1 | SW ₁ : 2, SW ₂ : 2 | 6.0 | 6.7 | 7.4 | V |
| NTE1572 | | SW ₁ : 1, SW ₂ : 2 | 6.0 | 6.7 | 7.4 | V |
| Max. Attenuation | ATT MAX | Note 19 | 60 | – | – | dB |
| DC Volume Gain | $G_{\text{ATT MAX}}$ | $R_A = 0$ | 4 | 6 | 8 | dB |
| ATT Characteristics | V_1 | Note 22 | 3.4 | 3.8 | 4.2 | V |
| | | Note 23 | 4.5 | 4.9 | 5.3 | V |
| Signal Leakage | V_{PT} | Note 20 | – | 1.0 | 3.0 | mV _{rms} |
| AF Amp Gain | $G_V \text{ AF}$ | Note 21 | – | 20 | – | dB |
| AF Amp Distortion | THD AF | $P_{23A} = 1V_{PP}$, 400Hz, SW ₃ : ON, ATT: –26dB Setting | – | 1.5 | – | % |
| AF Amp Max. Output Voltage | $V_{OAF\text{MAX}}$ | THD _{AF} = 5%, Note 21 | 1.5 | 2.0 | – | V_{rms} |
| AF Output DC Voltage NTE1570 | V_3 | SW ₁ : 2, SW ₂ : 2 | 6.7 | 7.7 | 8.8 | V |
| NTE1572 | | SW ₁ : 1, SW ₂ : 2 | 6.7 | 7.7 | 8.8 | V |

Notes:

- Note 1. V_{AGC} (P5 EXT. Applying Voltage) = 11.5V, PIF IN: $f = 58.75\text{MHz}$ 1kHz 30% AM Modulation. Adjust PIF input level (v_i) so that the detected output of P_{15A} with high impedance probe will be $0.8V_{P-P}$ and measure the input level.
- Note 2. $V_{AGC} = 4V$. Measure PIF input level (v_i) same as Note 1.
- Note 3. PIF IN: $f = 58.75\text{MHz}$ CW 15mV_{rms} . Measure DC level of P_{15} .
- Note 4. PIF IN: $f = 58.75\text{MHz}$, APL 100%, 87.5% AM modulation. P_5 : Ppen.
(1) Adjust PIF input level 50mV_{P-P} and measure the detected output level v_{01P-P} .
(2) Then increase the input level so that the detected output level will be $1.1 \times v_{01P-P}$ and measure the input level.
- Note 5. $V_{AGC} = 8V$. PIF IN: $58.75\text{MHz} \pm 10\text{MHz}$ variable or sweep 15mV_{rms} measure DC level of P_{15} .
- Note 6. $V_{AGC} = 8V$ (GR = 30dB). SG_1 : 58.75MHz CW, SG_2 : 58.65 to 40MHz variable.
(1) Setting output of SG_1 so that DC level of P_{15} will be $4V$.
(2) Setting output of SG_2 (58.65MHz) so that AC level of P_{15} will be $0.5V_{P-P}$.
(3) Decreasing frequency of SG_2 until AC level of P_{15} will be $0.35V_{P-P}$ (-3dB of $0.5V_{P-P}$) then read $f_{SG2} = F$, $f_{BW} = 58.75 - F$ MHz
- Note 7. SG_1 : 58.75MHz , 1kHz 80% AM modulation $100\text{mV}_{\text{rms}}$. SG_2, SG_3 : OFF. Setting V_{AGC} so that output AC level of P_{15} will be $2.7V_{P-P}$. Measure CL of P_{15} after setting to 0% AM of SG_1 .
- Note 8. Measure I_{2nd} of P_{15} same as Note 7.
- Note 9. $V_{AGC} = 8V$. SG_1 : 58.75MHz (P = Picture) $100\text{mV}_{\text{rms}}$. SG_2 : 54.25MHz (S = Sound) 32mV_{rms} (-10dB of SG_1). SG_3 : 55.17MHz (C = Chroma) 32mV_{rms} (-10dB of SG_1).
(1) Setting V_{AGC} so that the output tip level (lower) of P_{15} will be $3V$ DC.
(2) Measure the level difference (dB) between c-level and 920kHz level.
- Note 10. $V_{AGC} = 8V$. PIF IN: $f = 58.75\text{MHz}$ video signal (ramp) 87.5% AM 100mV_{P-P} . Setting ATT so that the sync tip level of P_{15} will be $2.5V$ DC. Measure DP and DG.
- Note 11. $V_{AGC} = 5V$, $f = 58.75\text{MHz}$. Measure R_{IN}, C_{IN} .
- Note 12. AFT sensitivity $\Delta F/\Delta(V_{13}-V_{14})$
(1) INT, AGC (P_5 Open)
(2) PIF Input: $58.75\text{MHz} \pm 1\text{MHz}$, CW 15mV_{rms} .
(3) Read the frequency (f_1) of PIF when $V_{13}-V_{14} = -1V$.
(4) Read the frequency (f_2) of PIF when $V_{13}-V_{14} = 1V$.
Then calculate $\Delta F/\Delta(V_{13}-V_{14}) = |f_1-f_2|$
- Note 13. $\Delta F_W, V_{13U}, V_{14U}, V_{13L}, V_{14L}$
(1) INT AGC (P_5 Open)
(2) PIF IN: $58.75\text{MHz} \pm 10\text{MHz}$ CW 15mV_{rms}
(3) 9pF at Pin16 should be shorted
(4) Read the frequency (f_1 or f_2) when the V_5 or V_6 reduced to 90% level of A or B with varying the frequency. Then band width is the difference from center frequency (f_0).
- Note 14. P_5 : Open. PIF IN: 58.75MHz CW 20mV_{rms} .
(1) Adjust the voltage of Pin3 so that the voltage of Pin4 will be $6V$ DC.
(2) Measure the voltage at Pin3.
- Note 15. P_5 : Open. PIF IN: 58.75MHz , 100% APL 87.5% AM modulation signal amplitude 50mV_{P-P} . Measure detected output voltage (White peak to sync tip).
- Note 16. P_5 : Open. SG_1 : 58.75MHz CW $100\text{mV}_{\text{rms}}$. SG_2 : 54.25MHz CW 25mV_{rms} . Measure SIF (4.5MHz) output voltage at P_{15} .
- Note 17. SIF IN: $f = 4.5\text{MHz}$, FM $f_{MOD} = 400\text{Hz}$, $\Delta f = \pm 25\text{kHz}$.
(1) Adjust SIF input level 100mV_{P-P} and measure the detected output level v_{OS} .
(2) Then decrease the input level so that the detected output level will be 3dB down of v_{OS} and measure the input level.

Notes (cont'd):

Note 18. Output Impedance

- (1) SIF IN: $f = 4.5\text{MHz}$, FM $f_{\text{MOD}} = 400\text{Hz}$, $\Delta f = \pm 25\text{kHz}$, $80\text{dB}\mu$.
- (2) At P_{23} read the V_{O1} at $R_X = \infty$, then read the R_X when recovered output become $V_{O1}/2$ with varying the R_X . The R_X is the output impedance.

Note 19. ATT MAX.

- (1) SIF IN: $f = 4.5\text{MHz}$, FM $f_{\text{MOD}} = 400\text{Hz}$, $\Delta f = \pm 25\text{kHz}$, $80\text{dB}\mu$.
- (2) Read the 400Hz component of V_{A1} at P_2 with $R_A = 0$, then read $V_{A1'}$ with $R_A = \infty$.

Note 20. V_{PT}

- (1) SIF IN: $f = 4.5\text{MHz}$, FM $f_{\text{MOD}} = 400\text{Hz}$, $\Delta f = \pm 25\text{kHz}$, $80\text{dB}\mu$.
- (2) Read the 400Hz component at P_3 .

Note 21. G_V AF

- (1) Apply 400Hz $0.1V_{\text{rms}}$ signal to P_2 .
- (2) Read the output voltage at P_3 .

Note 22. Read the 400Hz component of V_{A1} at P_2 with $R_A = 0$. Set R_A so that $V_{A1'} = 1/2V_{A1}$ (-6dB), then read DC voltage of Pin1 (V_1).

Note 23. Read the 400Hz component of V_{A1} at P_2 with $R_A = 0$. Set R_A so that $V_{A1'} = 3.16 \times 10^{-3}V_{A1}$ (-50dB), then read DC voltage of Pin1 (V_1).

Pin Connection Diagram

